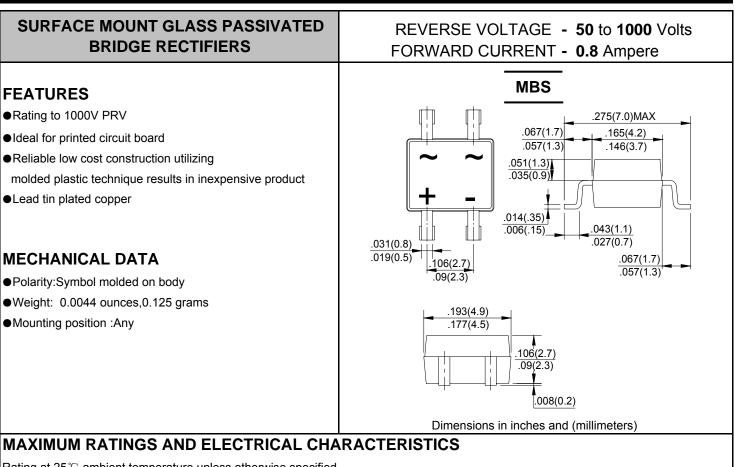


## B05S thru B10S



Rating at 25  $^\circ\!\!\!\!^\circ\mathbb{C}$  ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

SVMDOL							1	1
SYMBOL	B05S	B1S	B2S	B4S	B6S	B8S	B10S	UNIT
Vrrm	50	100	200	400	600	800	1000	V
Vrms	35	70	140	280	420	560	700	V
VDC	50	100	200	400	600	800	1000	V
l(AV)	0.8							А
IFSM	30							A
VF	1.1						V	
lĸ	5.0 500							μA
CJ	15							pF
Rejc	75							℃/W
TJ	-55 to +150							°C
Тѕтс	-55 to +150							°C
	VRRM VRMS VDC I(AV) IFSM VF IR CJ R0JC TJ	VRRM  50    VRMS  35    VDC  50    I(AV)	VRRM  50  100    VRMS  35  70    VDC  50  100    I(AV)	VRRM  50  100  200    VRMS  35  70  140    VDC  50  100  200    I(AV)	VRRM  50  100  200  400    VRMS  35  70  140  280    VDC  50  100  200  400    I(AV)  50  100  200  400    I(AV)  0.8  30  30    VF  1.1  30  500  500    VF  1.1  5.0  500  500    CJ  15  75  75  75    TJ  -55 to +150  -55 to +150  50	VRRM  50  100  200  400  600    VRMS  35  70  140  280  420    VDC  50  100  200  400  600    I(AV)  50  100  200  400  600    I(AV)  0.8  30  0.8  30  0.8    VF  1.1  30  1.1  1.1  1.1    IR  5.0  50  50	VRRM  50  100  200  400  600  800    VRMS  35  70  140  280  420  560    VDC  50  100  200  400  600  800    VDC  50  100  200  400  600  800    I(AV)  0.8  0.8  0.8  0.8  0.8  0.8    IFSM  30  0.8  30  0.8  0.8  0.8  0.8    VF  1.1  1	VRRM  50  100  200  400  600  800  1000    VRMS  35  70  140  280  420  560  700    VDC  50  100  200  400  600  800  1000    VDC  50  100  200  400  600  800  1000    I(AV)  0.8  0.8  30  1000  1000  1000  1000    I(AV)    30           IFSM    30                                      .

NOTES:1.Mounted on P.C. board.

2.Measured at1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to case

## RATING AND CHARACTERTIC CURVES B05S thru B10S

